

HIGH SPEED PRECISION QUAD OPERATIONAL AMPLIFIERS

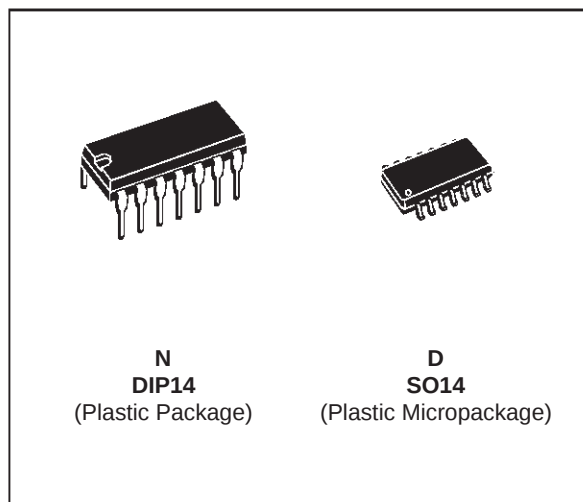
- LOW OFFSET VOLTAGE : 500 μ V max.
- LOW POWER CONSUMPTION
- SHORT CIRCUIT PROTECTION
- LOW DISTORTION, LOW NOISE
- HIGH GAIN-BANDWIDTH PRODUCT
- HIGH CHANNEL SEPARATION
- ESD INTERNAL PROTECTION

- **MACROMODEL** INCLUDED IN THIS SPECIFICATION

DESCRIPTION

The TS514 is a high performance quad operational amplifier with frequency and phase compensation built into the chip. The internal phase compensation allows stable operation as voltage follower in spite of its high gain-bandwidth products.

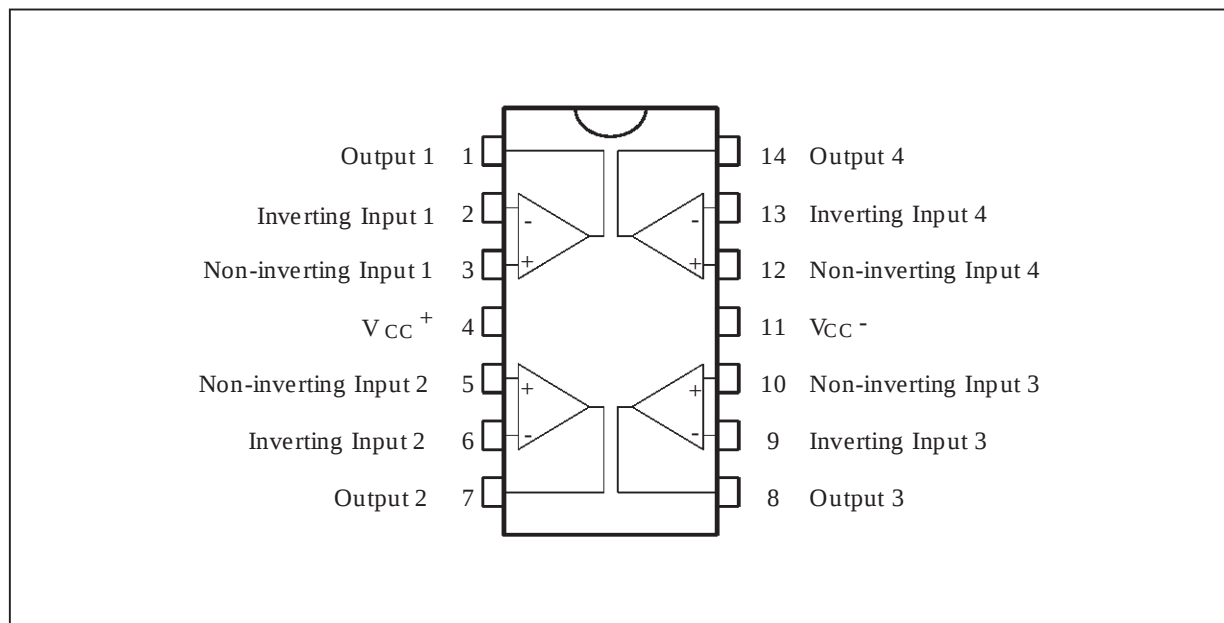
The circuit presents very stable electrical characteristics over the entire supply voltage range, and it particularly intended for professional and telecom applications (active filters, etc).



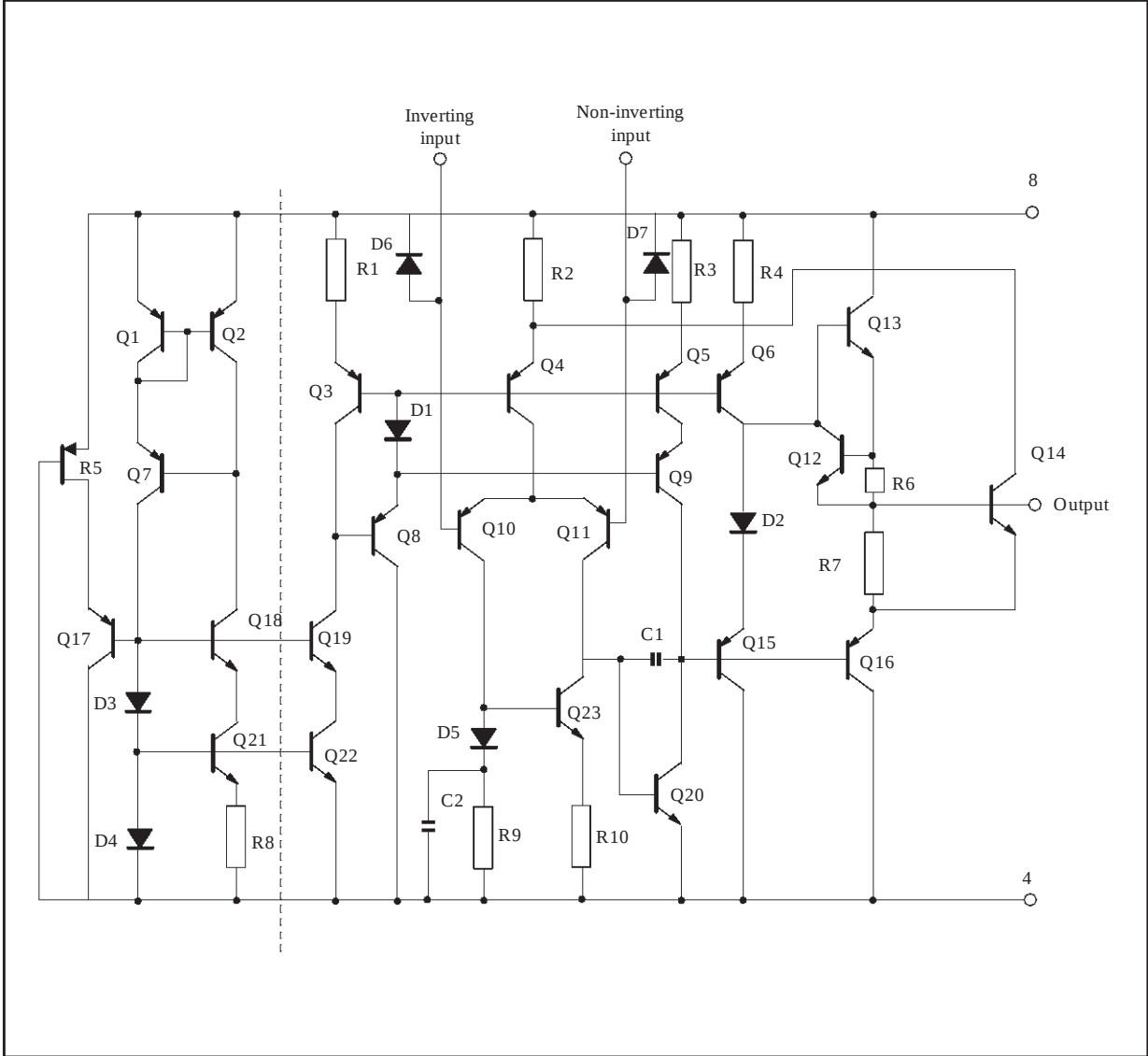
ORDER CODES

Part Number	Temperature Range	Package	
		N	D
TS514I	-40°C, +125°C	•	•
TS514AI	-40°C, +125°C	•	•

PIN CONNECTIONS (top view)



SCHEMATIC DIAGRAM (1/2 TS514)



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V _{CC}	Supply Voltage	±18	V
V _i	Input Voltage (positive) (negative)	+V _{CC} -V _{CC} - 0.5	V
V _{id}	Differential Input Voltage	± (V _{CC} - 1)	
T _{oper}	Operating Temperature Range	-40 to +125	°C
P _{tot}	Power Dissipation at T _{amb} = 70°C	400	mW
T _{stg}	Storage Temperature	-65 to 150	°C

ELECTRICAL CHARACTERISTICS ($V_{CC} = \pm 15V$, $T_{amb} = 25^{\circ}C$, unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
I_{CC}	Supply Current			1.4	2.4	mA
I_{ib}	Input Bias Current			50	150	nA
		$T_{min.} < T_{op} < T_{max.}$			300	nA
R_i	Input Resistance	$f = 1kHz$		1		M Ω
V_{io}	Input Offset Voltage	TS514 TS514A		0.5	2.5 0.5	mV
		$T_{min.} < T_{op} < T_{max.}$ TS514 TS514A			4 1.5	mV
DV_{io}	Input Offset Voltage Drift	$T_{min.} < T_{op} < T_{max.}$		5		$\mu V/^{\circ}C$
I_{io}	Input Offset Current			5	20	nA
		$T_{min.} < T_{op} < T_{max.}$			40	nA
DI_{io}	Input Offset Current Drift	$T_{min.} < T_{op} < T_{max.}$		0.08		$\frac{nA}{^{\circ}C}$
I_{os}	Output Short Circuit Current			23		mA
A_{vd}	Large Signal Voltage Gain	$R_L = 2k\Omega$ $V_{CC} = \pm 15V$ $V_{CC} = \pm 4V$	90	100 95		dB
GBP	Gain-bandwidth Product	$f = 100kHz$	1.8	3		MHz
e_n	Equivalent Input Noise Voltage	$f = 1kHz$ $R_s = 50\Omega$ $R_s = 1k\Omega$ $R_s = 10k\Omega$		8 10 18	15	$\frac{nV}{\sqrt{Hz}}$
THD	Total Harmonic Distortion	$A_V = 20dB$ $R_L = 2k\Omega$ $V_O = 2V_{PP}$ $f = 1kHz$		0.03	0.1	%
$\pm V_{opp}$	Output Voltage Swing	$R_L = 2k\Omega$ $V_{CC} = \pm 15V$ $V_{CC} = \pm 4V$	± 13	± 3		V
V_{opp}	Large Signal Voltage Swing	$R_L = 10k\Omega$ $f = 10kHz$		28		V_{PP}
SR	Slew Rate	Unity Gain, $R_L = 2k\Omega$	0.8	1.5		V/ μs
CMR	Common Mode Rejection Ratio	$V_{ic} = 10V$	90			dB
SVR	Supply Voltage Rejection Ratio	$V_{ic} = 1V$ $f = 100Hz$	90			dB
V_{O1}/V_{O2}	Channel Separation	$f = 1kHz$	100	120		dB

TS514,A

- SINGLE OR SPLIT SUPPLY OPERATION
- LOW POWER CONSUMPTION
- SHORT CIRCUIT PROTECTION
- LOW DISTORTION, LOW NOISE
- HIGH GAIN-BANDWIDTH PRODUCT
- HIGH CHANNEL SEPARATION

Applies to : TS514i,AI

** Standard Linear Ics Macromodels, 1993.

** CONNECTIONS :

* 1 INVERTING INPUT

* 2 NON-INVERTING INPUT

* 3 OUTPUT

* 4 POSITIVE POWER SUPPLY

* 5 NEGATIVE POWER SUPPLY

.SUBCKT TS514 1 3 2 4 5 (analog)

.MODEL MDTH D IS=1E-8 KF=6.647807E-16 CJO=10F

* INPUT STAGE

CIP 2 5 1.000000E-12

CIN 1 5 1.000000E-12

EIP 10 5 2 5 1

EIN 16 5 1 5 1

RIP 10 11 1.300000E+01

RIN 15 16 1.300000E+01

RIS 11 15 6.437882E+01

DIP 11 12 MDTH 400E-12

DIN 15 14 MDTH 400E-12

VOFP 12 13 DC 0

VOFN 13 14 DC 0

IPOL 13 5 2.000000E-05

CPS 11 15 9.75E-10

DINN 17 13 MDTH 400E-12

VIN 17 5 0.000000E+00

DINR 15 18 MDTH 400E-12

VIP 4 18 1.500000E+00

FCP 4 5 VOFP 1.525000E+01

FCN 5 4 VOFN 1.525000E+01

FIBP 2 5 VOFN 5.000000E-03

FIBN 5 1 VOFP 5.000000E-03

* AMPLIFYING STAGE

FIP 5 19 VOFP 1.125000E+03

FIN 5 19 VOFN 1.125000E+03

RG1 19 5 6.512062E+05

RG2 19 4 6.512062E+05

CC 19 29 1.500000E-08

HZTP 30 29 VOFP 8.944787E+02

HZTN 5 30 VOFN 8.944787E+02

DOPM 19 22 MDTH 400E-12

DONM 21 19 MDTH 400E-12

HOPM 22 28 VOUT 6.521739E+03

VIPM 28 4 1.500000E+02

HONM 21 27 VOUT 6.521739E+03

VINM 5 27 1.500000E+02

GCOMP 5 4 4 5 7.485029E-04

RPM1 5 80 1E+09

RPM2 4 80 1E+09

GAVPH 5 82 19 80 2.99E-03

RAVPHGH 82 4 668

RAVPHGB 82 5 668

RAVPHDH 82 83 1000

RAVPHDB 82 84 1000

CAVPHH 4 83 0.352E-09

CAVPHB 5 84 0.352E-09

EOUT 26 23 82 5 1

VOUT 23 5 0

ROUT 26 3 150

COUT 3 5 1.000000E-12

DOP 19 25 MDTH 400E-12

VOP 4 25 1.785252E+00

DON 24 19 MDTH 400E-12

VON 24 5 1.785252E+00

.ENDS

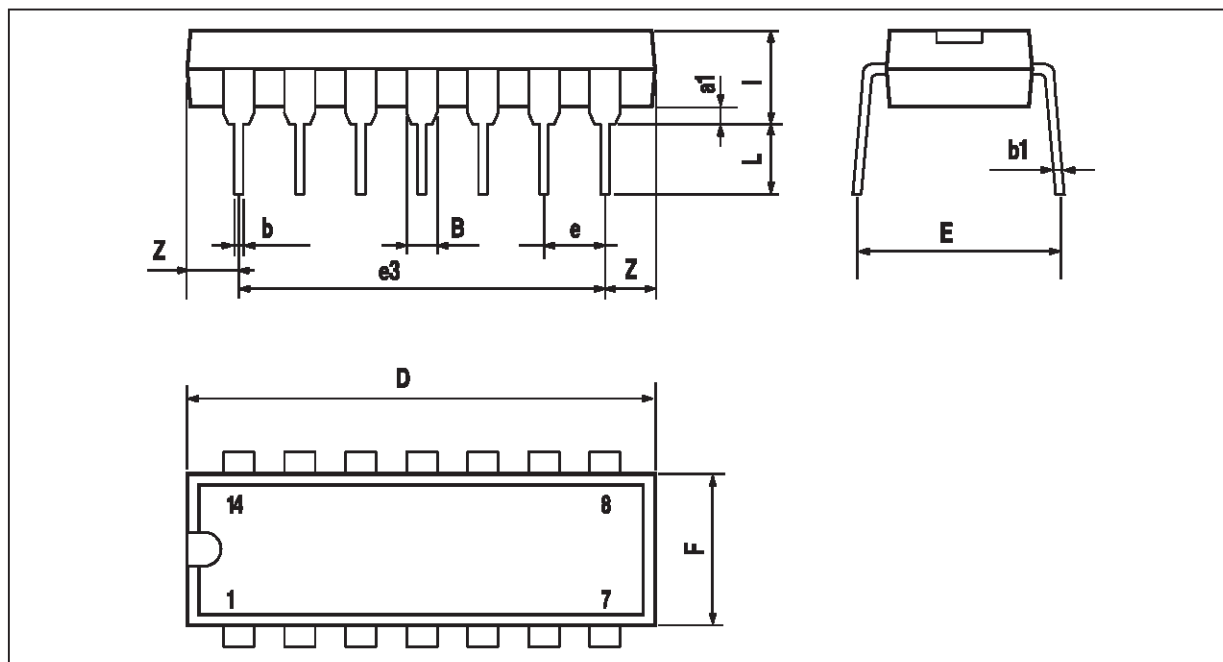
ELECTRICAL CHARACTERISTICS

$V_{CC} = \pm 15V$, $T_{amb} = 25^{\circ}C$ (unless otherwise specified)

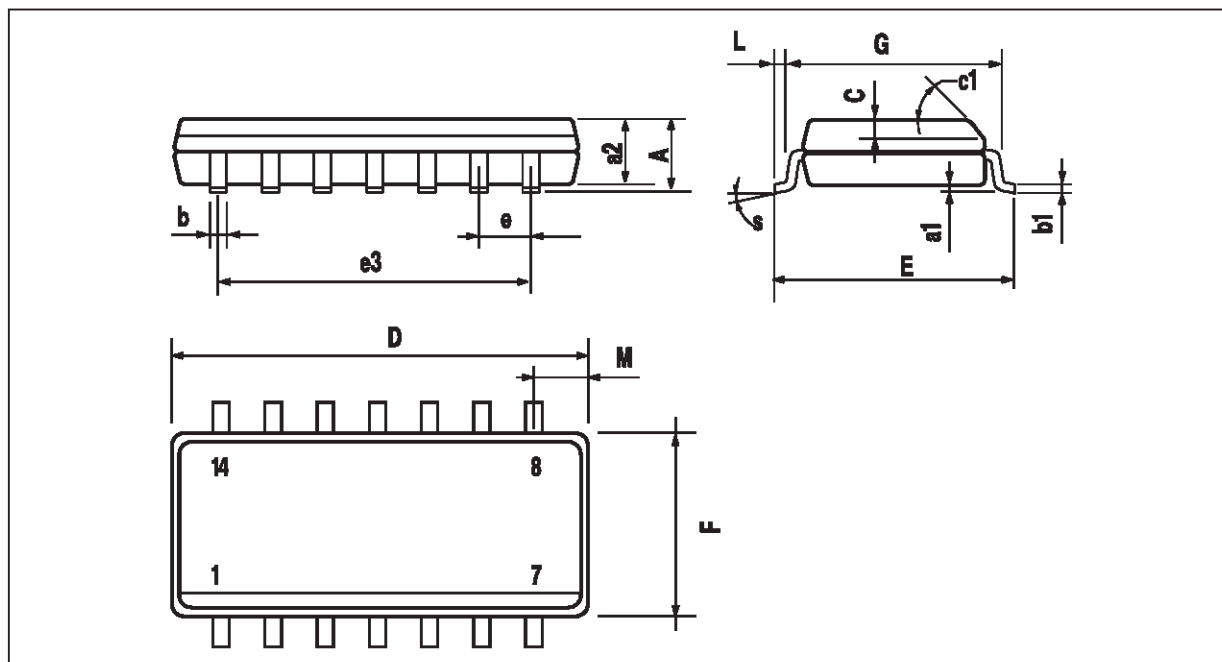
Symbol	Conditions	Value	Unit
V_{io}		0	mV
A_{vd}	$R_L = 2k\Omega$	94	V/mV
I_{CC}	No load, per operator	325	μA
V_{icm}		-15 to 13.5	V
V_{OH}	$R_L = 2k\Omega$	+13	V
V_{OL}	$R_L = 2k\Omega$	-13	V
I_{sink}	$V_O = 0V$	24	mA
I_{source}	$V_O = 0V$	24	mA
GBP	$R_L = 2k\Omega$, $C_L = 100pF$	3	MHz
SR	$R_L = 2k\Omega$, $C_L = 100pF$	1.4	V/ μs
θ_m	$R_L = 2k\Omega$, $C_L = 100pF$	55	Degrees

PACKAGE MECHANICAL DATA

14 PINS - PLASTIC DIP



Dim.	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
a_1	0.51			0.020		
B	1.39		1.65	0.055		0.065
b		0.5			0.020	
b_1		0.25			0.010	
D			20			0.787
E		8.5			0.335	
e		2.54			0.100	
e_3		15.24			0.600	
F			7.1			0.280
i			5.1			0.201
L		3.3			0.130	
Z	1.27		2.54	0.050		0.100

PACKAGE MECHANICAL DATA**14 PINS - PLASTIC MICROPACKAGE (SO)**

Dim.	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A			1.75			0.069
a1	0.1		0.2	0.004		0.008
a2			1.6			0.063
b	0.35		0.46	0.014		0.018
b1	0.19		0.25	0.007		0.010
C		0.5			0.020	
c1	45° (typ.)					
D	8.55		8.75	0.336		0.334
E	5.8		6.2	0.228		0.244
e		1.27			0.050	
e3		7.62			0.300	
F	3.8		4.0	0.150		0.157
G	4.6		5.3	0.181		0.208
L	0.5		1.27	0.020		0.050
M			0.68			0.027
S	8° (max.)					

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